Hex buffer/line driver; 3-state; inverting Rev. 6 — 17 February 2021

1. General description

The 74HC366; 74HCT366 is a hex inverting buffer/line driver with 3-state outputs controlled by the output enable inputs (\overline{OEn}). A HIGH on \overline{OEn} causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- Inverting outputs
- Input levels:
 - For 74HC366: CMOS level
 - For 74HCT366: TTL level
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

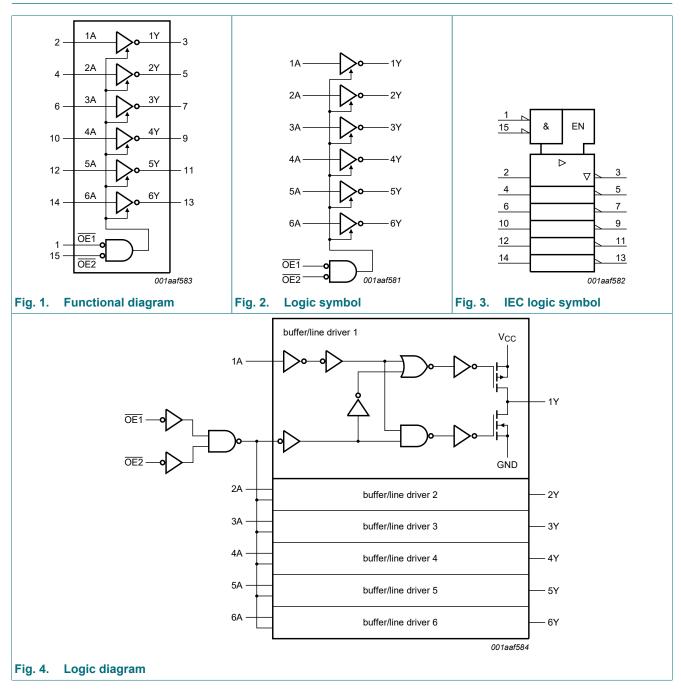
3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC366D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT366D				
74HC366PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74HCT366PW			body width 4.4 mm	

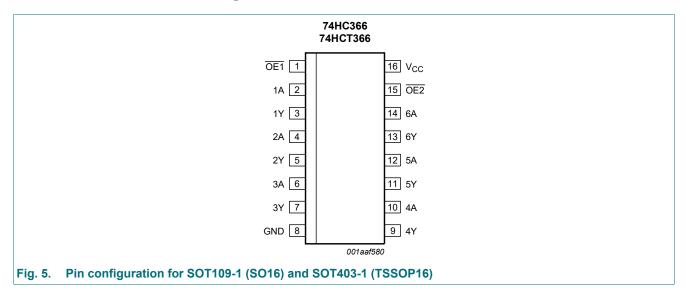
nexperia

4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
OE1, OE2	1, 15	output enable input (active LOW)
1A, 2A, 3A, 4A, 5A, 6A	2, 4, 6, 10, 12, 14	data input
1Y, 2Y, 3Y, 4Y, 5Y, 6Y	3, 5, 7, 9, 11, 13	data output
GND	8	ground (0 V)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

		Input	Output
OE1	OE2	nA	nY
L	L	L	Н
L	L	Н	L
Х	Н	Х	Z
Н	Х	Х	Z

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _{ОК}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	V_{O} = -0.5 V to (V _{CC} + 0.5 V)	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-	-70	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[1]	-	500	mW

For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.
 For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC366			7	Unit		
			Min	Тур	Мах	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics 74HC366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	5 °C	·	I			
VIH	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V 1.5 1.2 - V V _{CC} = 4.5 V 3.15 2.4 - V V _{CC} = 6.0 V 4.2 3.2 - V V _{CC} = 4.5 V - 0.8 0.5 V V _{CC} = 4.5 V - 0.8 0.5 V V _{CC} = 4.5 V - 2.1 1.35 V V _{CC} = 6.0 V - 2.8 1.8 V v _{CC} = 6.0 V - 2.8 1.8 V v _{CC} = 6.0 V - 2.8 1.8 V v _I = 0.0 µA; V _{CC} = 2.0 V 1.9 2.0 - V I ₀ = -20 µA; V _{CC} = 4.5 V 4.4 4.5 - V I ₀ = -20 µA; V _{CC} = 6.0 V 5.9 6.0 - V I ₀ = -20 µA; V _{CC} = 6.0 V 5.48 5.81 - V I ₀ = -20 µA; V _{CC} = 6.0 V 5.48 5.81 - V I ₀ = 20 µA; V _{CC} = 6.0 V - 0 0.1 V				
		V _{CC} = 4.5 V	-	2.1	2 - 2 - 2 - 3 0.5 1.35 3 3 1.8 - - 0 - 0 - 0 - 0 - 0 - 1 - 0 - 1 - 0 - 1 - 0.1 0.1 0.1 0.1 5 0.266 ±0.1 ±0.5 8.0 8.0	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	-	-	-	
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	0	1.8 - - - - - 0.1 0.1 0.26 0.26	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μA
I _{CC}	supply current	$V_{I} = V_{CC} \text{ or GND; } I_{O} = 0 \text{ A; } V_{CC} = 6.0 \text{ V}$	-	-	8.0	μA
CI	input capacitance		-	3.5	-	pF

Hex buffer/line driver; 3-state; inverting

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	10 °C to +85 °C	·				
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{ОН}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	- - 0.5 1.35 1.35 1.3 1.3 1.3 1.3 1.3 1.3 1.3 1.3 1.3 1.3 1.3 1.3 1.3 1.3 0.1 0.1 0.1 0.1 0.1 0.33 0.33 1.35 1.3 0.33 0.33 0.33 0.33 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35 1.35	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.34	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.33	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V;	-	-	±1.0	μA
OZ	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±5.0	μA
СС	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
T _{amb} = -4	40 °C to +125 °C	I				1
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	.5	-	V
		V _{CC} = 4.5 V	3.15	-	±5.0 80 - - - 0.5	V
		V _{CC} = 6.0 V	4.2	-		V
VIL	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{он}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		$I_0 = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.2	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		$I_0 = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	_	0.1	V
		$I_0 = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	-	_	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	-		V
		$I_0 = 6.0 \text{ mA; } V_{CC} = 4.5 \text{ V}$	-	_		V
		$I_0 = 7.8 \text{ mA; } V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
1	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	_	-		μA
oz	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 6.0 \text{ V}$		_		•
	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V				μA

Table 7. Static characteristics 74HCT366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
VIH	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	4.5	-	V
		I _O = -6.0 mA	3.98	4.32	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = 20 μA	-	0	1.2 0.8 1.2 0.8 4.5 - 4.32 - 0 0.1 0 0.1 0.16 0.26 - ±0.1 - ±0.5 - 8.0 100 360 100 360 90 320 3.5 - - 0.8 - 0.8 - - - 0.8 - - - - - 0.8 - - - - - - - - - - - - - - - - - - - - - - - - - - - - - - - - -<	V
		I _O = 6.0 mA	-	0.16	0.26	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 5.5 \text{ V}$	-	-	±0.5	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$				
		pins nA	-	100	360	μA
		pin OE1	-	100	360	μA
		pin OE2	-	90	320	μA
CI	input capacitance		-	3.5	-	pF
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = -20 μA	4.4	-	-	V
		I _O = -6.0 mA	3.84	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.33	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$			±5.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $I_O = 0 A$				
		pins nA	-	-	450	μA
		pin OE1	-	-	450	μA
		pin OE2	-	-	400	μA

Hex buffer/line driver; 3-state; inverting

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = -20 μA	4.4	-	-	V
		I _O = -6.0 mA	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.4	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±10.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$				
		pins nA	-	-	490	μA
		pin OE1	-	-	490	μA
		pin OE2	-	-	441	μA

10. Dynamic characteristics

Table 8. Dynamic characteristics 74HC366

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; see test circuit Fig. 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C		I		1	1	1
t _{pd}	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 2.0 V		-	33	Max 100 20 - 17 150 30 26 12 10 12 10 10 12 10 12 10 12 10 12 10 10	ns
		V _{CC} = 4.5 V		-	12		ns
		V _{CC} = 5 V; C _L = 15 pF		-	10	-	ns
		V _{CC} = 6.0 V		-	10	17	ns
t _{en}	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	44	150	ns
		V _{CC} = 4.5 V		-	16	30	ns
		V _{CC} = 6.0 V		-	13	26	ns
t _{dis}	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	55	150	ns
		V _{CC} = 4.5 V		-	20	30	ns
		V _{CC} = 6.0 V		-	16	26	ns
t _t	transition time	see <u>Fig. 6</u>	[4]				
		V _{CC} = 2.0 V		-	14	60	ns
		V _{CC} = 4.5 V		-	5	12	ns
		V _{CC} = 6.0 V		-	4	10	ns
C _{PD}	power dissipation capacitance	per buffer; V_I = GND to V_{CC}	[5]	-	30	-	pF

Hex buffer/line driver; 3-state; inverting

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +85 °C						-
pd	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 2.0 V		-	-	125	ns
		V _{CC} = 4.5 V		-	-	25	ns
		V _{CC} = 6.0 V		-	-	21	ns
en	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
dis	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
t	transition time	see <u>Fig. 6</u>	[4]				
		V _{CC} = 2.0 V		-	-	75	ns
		V _{CC} = 4.5 V		-	-	15	ns
		V _{CC} = 6.0 V		-	-	13	ns
T _{amb} = -4	40 °C to +125 °C				I		
pd	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 2.0 V		-	-	150	ns
		V _{CC} = 4.5 V		-	-	30	ns
		V _{CC} = 6.0 V		-	-	26	ns
en	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
dis	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
t	transition time	see <u>Fig. 6</u>	[4]				
		V _{CC} = 2.0 V		-	-	90	ns
		V _{CC} = 4.5 V		-	-	18	ns
		V _{CC} = 6.0 V		-	-	15	ns

 $[1] \quad t_{pd} \text{ is the same as } t_{PHL} \text{ and } t_{PLH}.$

[2] \dot{t}_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[4] t_t is the same as t_{THL} and t_{LLH} . [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

Table 9. Dynamic characteristics 74HCT366

Voltages are referenced to GND (ground = 0 V); C_1 = 50 pF unless otherwise specified; see test circuit Fig. 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C						
t _{pd}	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 4.5 V		-	13	24	ns
		V _{CC} = 5 V; C _L = 15 pF		-	11	-	ns
t _{en}	enable time	OEn to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[2]	-	16	35	ns
t _{dis}	disable time	OEn to nY; V _{CC} = 4.5 V; see Fig. 7	[3]	-	20	35	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	5	12	ns
C _{PD}	power dissipation capacitance	per buffer; V_I = GND to (V_{CC} - 1.5 V)	[5]	-	30	-	pF
T _{amb} = -4	40 °C to +85 °C						
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see <u>Fig. 6</u>	[1]	-	-	30	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[2]	-	-	44	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[3]	-	-	44	ns
tt	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	-	15	ns
T _{amb} = -4	40 °C to +125 °C	·					
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see <u>Fig. 6</u>	[1]	-	-	36	ns
t _{en}	enable time	OEn to nY; V _{CC} = 4.5 V; see Fig. 7	[2]	-	-	53	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[3]	-	-	53	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	-	18	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and $t_{\text{PLZ}}.$

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ}.
[4] t_t is the same as t_{THL} and t_{TLH}.
[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW). P_D = C_{PD} x V_{CC}² x f_i x N + Σ(C_L x V_{CC}² x f_o) where: f_i = input frequency in MHz;

 f_o = output frequency in MHz;

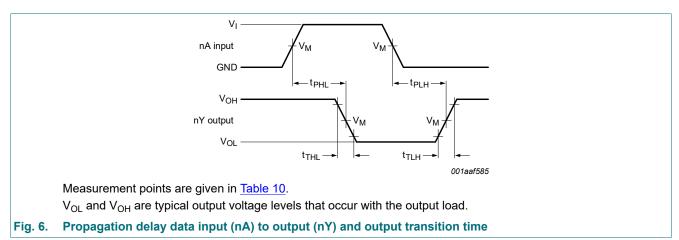
 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Hex buffer/line driver; 3-state; inverting



10.1. Waveforms and test circuit

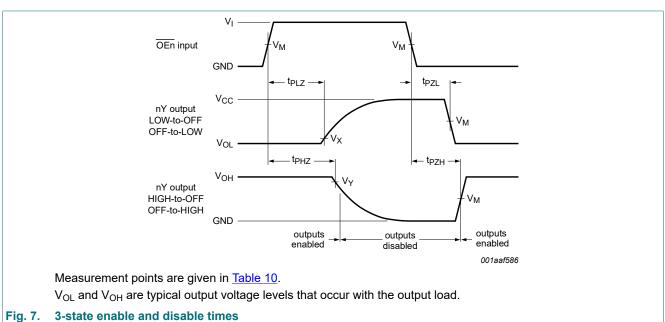


Table 10. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC366	0.5V _{CC}	0.5V _{CC}	0.1 x V _{CC}	0.9 x V _{CC}
74HCT366	1.3 V	1.3 V	0.1 x V _{CC}	0.9 x V _{CC}

Hex buffer/line driver; 3-state; inverting

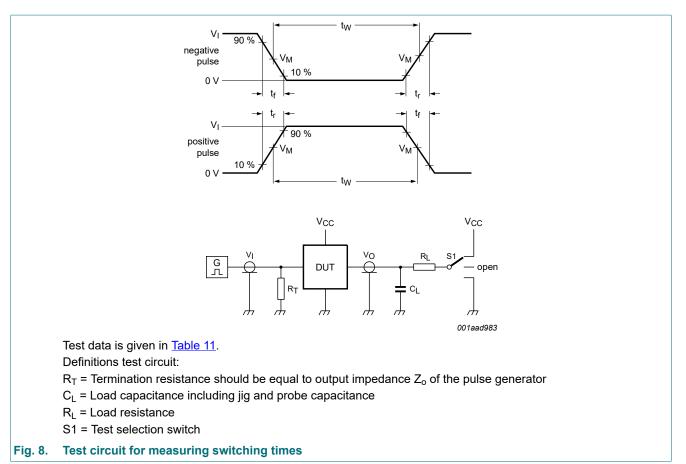


Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC366	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74HCT366	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}

11. Package outline

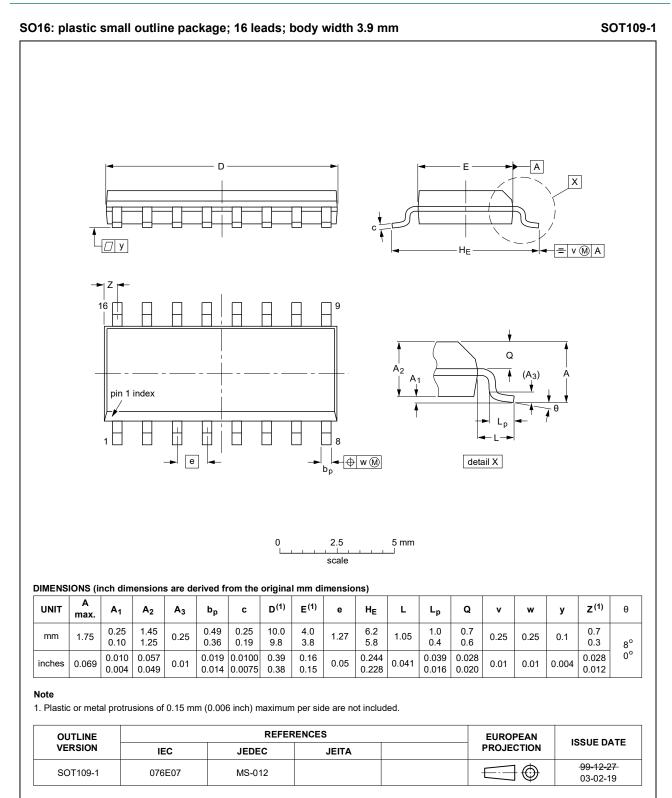


Fig. 9. Package outline SOT109-1 (SO16)

74HC_HCT366

Hex buffer/line driver; 3-state; inverting

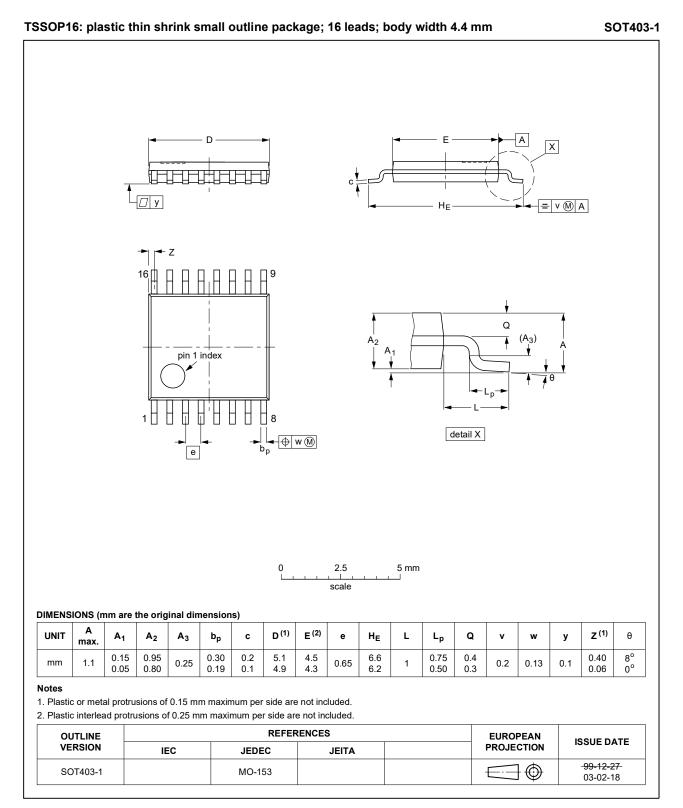


Fig. 10. Package outline SOT403-1 (TSSOP16)

⁷⁴HC_HCT366

12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

13. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT366 v.6	20210217	Product data sheet	-	74HC_HCT366 v.5	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. <u>Section 2</u> updated. <u>Section 7</u>: Derating values for P_{tot} total power dissipation updated. Type number 74HCT366DB (SOT338-1 / SSOP16) removed. 				
74HC_HCT366 v.5	20160202	Product data sheet	-	74HC_HCT366 v.4	
Modifications:	Type numbers	74HC366N and 74HCT366N	(SOT38-4) removed	•	
74HC_HCT366 v.4	20120904	Product data sheet	-	74HC_HCT366 v.3	
Modifications:	Legal pages updated.				
74HC_HCT366 v.3	20061121	Product data sheet	-	74HC_HCT366_CNV v.2	
74HC_HCT366_CNV v.2	19901201	Product specification	-	-	

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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Hex buffer/line driver; 3-state; inverting

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